

CMIDSH1-4  
CMIDSH1-6

SURFACE MOUNT  
LOW V<sub>F</sub>  
SILICON SCHOTTKY RECTIFIER  
1 AMP, 40 AND 60 VOLTS

**SUPERmini™**



SOD-323FL CASE

**FEATURES:**

- Low package profile
- High reverse voltage capability
- Low leakage current

**MAXIMUM RATINGS: (T<sub>A</sub>=25°C)**

Peak Repetitive Reverse Voltage

Average Forward Current (T<sub>L</sub>=110°C)

Peak Forward Surge Current, t<sub>p</sub>=8.3ms

Operating and Storage Junction Temperature

Thermal Resistance (Note 1)



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**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMIDSH1-4 and CMIDSH1-6 are silicon Schottky rectifiers packaged in a space saving flat lead, low profile SOD-323FL case. These SUPERmini™ devices have been designed for applications requiring a low forward voltage drop.

**MARKING CODES: CMIDSH1-4: C14  
CMIDSH1-6: C16**

**APPLICATIONS:**

- DC-DC converters
- Voltage clamping
- Reverse polarity protection
- General purpose rectification

SYMBOL	CMIDSH1-4		CMIDSH1-6		UNITS
	TYP	MAX	TYP	MAX	
V <sub>RRM</sub>			40	60	V
I <sub>O</sub>			1.0		A
I <sub>FSM</sub>			20		A
T <sub>J</sub> , T <sub>stg</sub>			-65 to +150		°C
Θ <sub>JA</sub>			405		°C/W

Notes: (1) FR-4 epoxy PCB with minimum copper pad area.

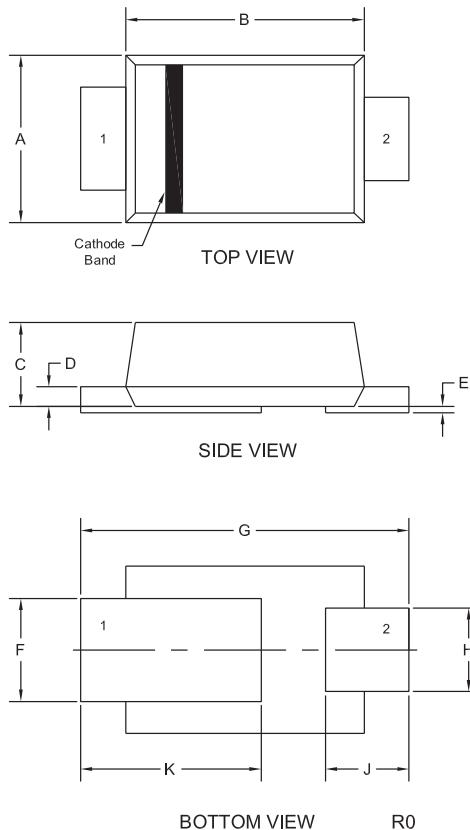
R2 (20-April 2012)

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LOW  $V_F$   
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**SOD-323FL CASE - MECHANICAL OUTLINE**



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.047	0.055	1.20	1.40
B	0.068	0.077	1.75	1.95
C	0.021	0.030	0.55	0.75
D	0.004	0.008	0.10	0.20
E	-	0.004	-	0.10
F	0.025	0.038	0.65	0.95
G	0.090	0.107	2.30	2.70
H	0.017	0.030	0.45	0.75
J	0.015	0.032	0.40	0.80
K	0.045	0.061	1.15	1.55

SOD-323FL (REV:R0)

**LEAD CODE:**

- 1) Cathode
- 2) Anode

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